

Observation of Pulse Compression in Photonic Crystal Coupled Cavity Waveguides

T. J. Karle, *Student Member, IEEE*, Y. J. Chai, C. N. Morgan, *Member, IEEE*, I. H. White, *Senior Member, IEEE*, and T. F. Krauss

Abstract—We demonstrate the compression of picosecond pulses using the large group velocity dispersion available from planar photonic crystal (PhC) coupled cavity waveguides (CCWs). A maximum pulsewidth reduction of 40%, from 1.91 to 1.17 ps, is achieved, in transmission through an 8- μm -long planar PhC waveguide. The equivalent dispersion value is $>10^6$ times larger than that available from standard single-mode fiber, at the pulse center wavelength of 1536 nm. The device performance is analyzed with the aid of both two-dimensional (2-D) eigenmode expansion and 2-D finite-difference time-domain (FDTD) models. The models included the material dispersion of the GaAs/AlGaAs heterostructure, into which the PhCs are etched, and show remarkable agreement with experiment.

Index Terms—Band-gap structures, fabrication, optical planar waveguides, optical pulse compression.

I. INTRODUCTION

PLANAR integration of two-dimensional (2-D) photonic crystals (PhCs) with conventional waveguides offers the potential of high-density integrated optics with significant functionality. The periodically modulated, strong refractive index contrast of the PhCs exhibits large spatial and temporal dispersion [1], offering a route to ultracompact component design. Of particular interest to optical communications are devices designed to operate in the 1300 and 1550 nm wavelength windows, where PhC filtering and dispersion compensation could impact upon future high-speed transmission systems. Such devices have previously been studied predominantly in terms of their CW transmission characteristics, whereas their dynamic performance has not yet been fully characterized. This paper demonstrates for the first time, to the author's knowledge, compression of pulses by transmission through 2-D PhCs. Critical problems such as out-of-plane losses and impedance mismatch remain to be resolved.

II. DEVICE CONCEPT AND DESIGN

Coupled cavity waveguides (CCWs) [2] are a subclass of PhC waveguides, a hybridization of line and point defects. The

Manuscript received May 19, 2003; revised October 22, 2003. This work was supported by the ESPRC through the Ultrafast Photonics Collaboration (UPC) and the Nanoelectronics Research Centre, University of Glasgow. The work of T. J. Karle is supported by a CASE award from Agilent Technologies.

T. J. Karle and T. F. Krauss are with the Ultrafast Photonics Collaboration, School of Physics and Astronomy, University of St. Andrews, Fife, KY16 9SS, U.K.

Y. J. Chai, C. N. Morgan, and I. H. White are with the Ultrafast Photonics Collaboration, Centre for Photonic Communication Systems Research, Engineering Department, Cambridge University, Cambridge, CB2 1PZ, U.K.

Digital Object Identifier 10.1109/JLT.2004.824393

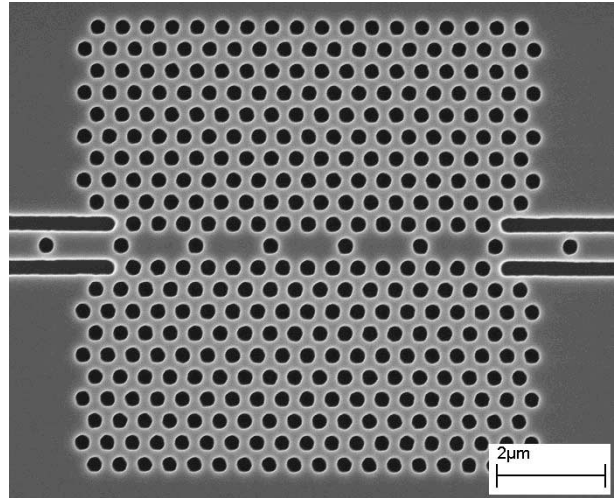


Fig. 1. Device under test, an L2in1 CCW, with lattice constant $a = 460$ nm. Coupling is facilitated via deeply etched trenches defining input/output ridge waveguides.

waveguiding mechanism uses the coupling between the eigenmodes of the individual cavities along a chain of adjacent cavities. Light is localized within the various normal modes of the chain, providing strong temporal dispersion. Such structures afford tailored group velocity dispersion in the construction of optical delay lines, filters, routers, pulse shapers, and dispersion compensators.

The dielectric configuration of the device under test is shown in Fig. 1. It consists of an L2in1 CCW, a line cavity with a unit cell comprising two missing holes with one spacer hole. Vertical confinement is provided by a GaAs/AlGaAs heterostructure. Devices are fabricated by electron beam lithography and reactive ion etching as in [3], although here the transfer of the SiO_2 mask into the semiconductor is facilitated using a chemically assisted ion beam etching (CAIBE) process, with Cl_2 as the reactive gas. This provides a deeper etch of $1.5 \mu\text{m}$ [as opposed to the $1 \mu\text{m}$ obtained previously using reactive ion etching (RIE)] promoting lower losses, by reducing the magnitude of the field component which can be scattered into the substrate. A set of six similar samples were prepared with small (8 nm) steps of lattice period in order to match the transmission band to that of the erbium doped fiber amplifier (EDFA) C-band, around 1550 nm. A constant filling factor was maintained, with a radius of $r = 1/3a$, where a is the lattice constant of the PhC.

III. DEVICE OPERATION

Calculation of the photonic band structure of the unit cell, for TE polarization, was performed using the MIT Bands software

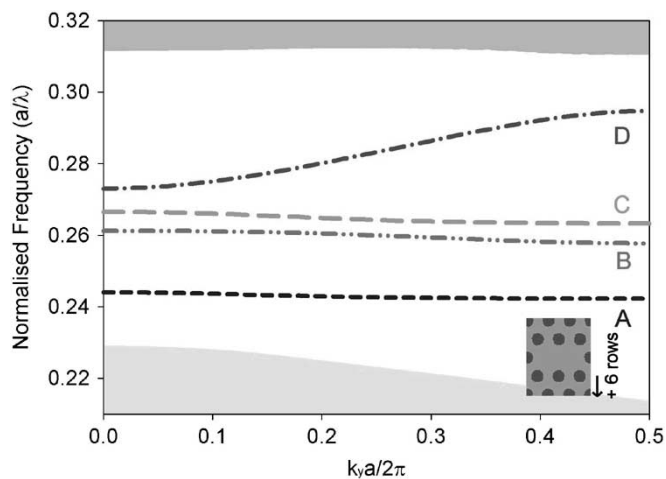


Fig. 2. Photonic bandstructure for infinite repetition of the inset super cell, four modes can be seen spanning the bandgap ($u = 0.23$ – 0.31).

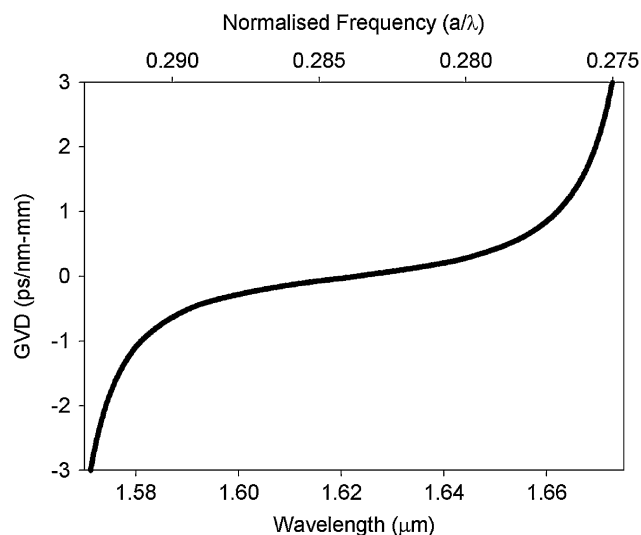


Fig. 3. GVD for mode D, calculated from above bandstructure.

[4], and shows (see Fig. 2) a set of four modes which span the bandgap ($u = a/\lambda = 0.23$ – 0.31 , where u is normalized frequency, $r = 1/3a$, and refractive index $n = 3.29$). Two of these modes have even symmetry (tripole, $u_A = 0.244$ and quadropole, $u_D = 0.295$) with respect to the waveguide (z -axis, Γ -K) and the others have odd symmetry (split quadropole, $u_B = 0.261$, $u_C = 0.267$). The dispersion characteristic of each mode exhibits a characteristic S shape. The group velocity dispersion (GVD), the second derivative of the ω - k plot, was calculated for mode D (plotted in Fig. 3). Significant slowing of the group velocity can be seen at the edge of each of the transmission bands. Choice of mode and operating point allows us access to both regions of positive or negative group velocity dispersion, of the order $GVD \sim \pm 1$ ps/nm-mm. In practice, we have only been able to couple significant power through the widest of these even modes (D) and we will concentrate on this mode in the following investigation. It is noted that as these modes all lie above the light line of the $\text{Al}_{0.6}\text{Ga}_{0.4}\text{As}$ buffer, coupling to radiation modes is possible [5].

The results of the bandstructure calculation are valid for an infinitely long, lossless CCW. Our experiments focus upon a very

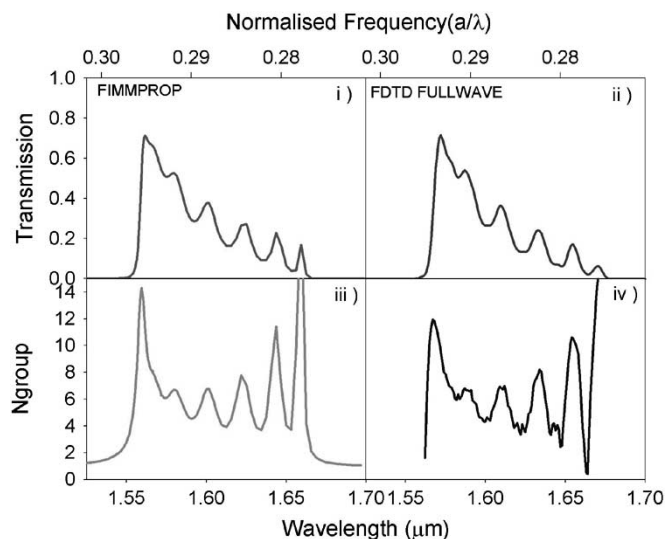


Fig. 4. Modeled transmission and group index from Fimmprop EME/Fullwave FDTD models, respectively.

short chain of cavities. In order to model the behavior of the finite length device two models were constructed. Both models include short $2\text{-}\mu\text{m}$ sections of input and output waveguides. The continuous wave (CW) behavior was modeled by a 2-D FDTD beam propagation tool (FullWave—RSoft, Inc.) and by 2-D eigenmode expansion (Fimmprop—Photon Design). The convergence of both models was verified. The transmitted amplitude and phase of the fundamental even modes were recovered. Both models were shown to reproduce the characteristic shape of the transmission band of mode D. The material dispersion of the GaAs/AlGaAs heterostructure waveguide is corrected for in each model. The equivalent index of refraction of the vertical slab mode was solved independently and is used as a 2-D approximation [6]. Experimentally the transmission band is shifted to a higher frequency than that predicted by the 2-D models, this would indicate that the field is concentrated in a medium of lower refractive index than anticipated. We are attempting to determine the nature of this frequency shift; two plausible candidates are either that the material has very slightly oxidised or that the optical mode profile is distributed further into the air and $\text{Al}_{0.6}\text{Ga}_{0.4}\text{As}$ buffer when compared to the slab mode. Understanding this will allow us to feedback into the design process to further correct each model.

An effective index approach then defines a group index $N_g = n - \lambda(dn/d\lambda)$ plotted in Fig. 4, together with the transmitted power. The seven cavities in this CCW should produce seven individual peaks in the transmission spectrum, corresponding to the seven normal modes of the system. We do observe these individual modes, although the first two appear to be merged as indicated by the shoulder on the long wavelength side of the highest frequency peak. The ripple in the group velocity is very pronounced across the transmission peak, due to the short nature of the crystal and high impedance. This should in principle allow pulse compression/dilation at various points across the feature. The GVD for this finite structure is then obtained from, $GVD = (1/c)(dN_g/d\lambda)$. This is displayed for the crest of the transmission peak in Fig. 5. Peak values of ± 10 ps/nm-mm are available and coincide with regimes of high transmission en-

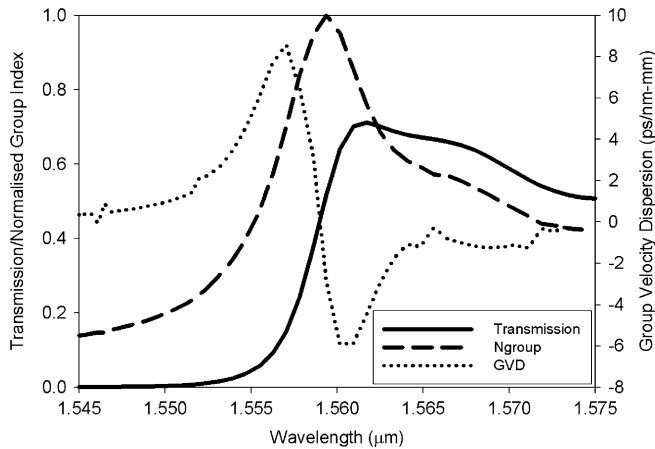


Fig. 5. GVD obtained from Fimmprop data across crest of transmission peak.

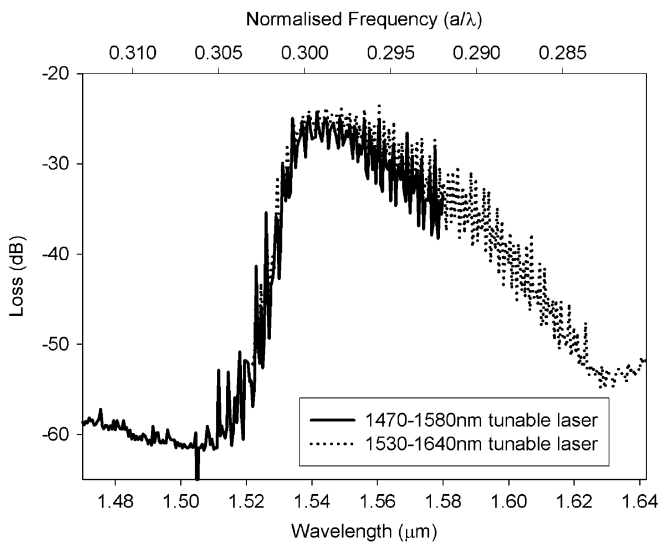


Fig. 6. CW transmission spectrum of mode D for device with lattice constant $a = 460$ nm.

abling experimental verification via pulse propagation measurements.

The TE ($\mathbf{E} \parallel$ crystal plane) CW transmission characteristic of the ($a = 460$ nm) device is shown in Fig. 6. A strong rising edge is observed between 1520 and 1540 nm, followed by a slow falling edge. The asymmetry of this band is attributed to the two matching holes that were added to the mask design, in an attempt to impedance match the waveguide. In brief, the transmission band corresponds to the overlapping normal modes of the chain of cavities (with one mode provided per cavity). The distribution of optical power in each normal mode favors the dielectric at the higher frequency band edge and favors the air at the lower frequency band edge. The resonant frequency of the end cavities overlaps the higher frequency band edge, providing efficient coupling to this normal mode and inhibiting coupling at the lower frequency band edge. The result is the characteristic triangular spectrum. The noise apparent on this CW spectrum is due to Fabry-Perot resonances arising from the reflections between the cleaved GaAs facets and the ridge waveguide/PhC interfaces. This can have particularly strong spectral filtering effects on pulses with durations greater than a single round trip

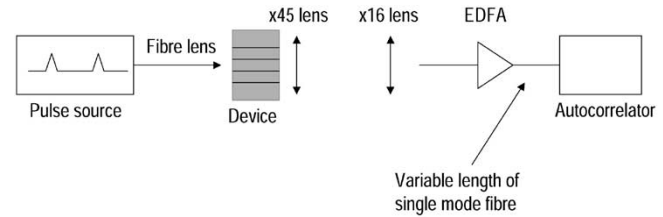


Fig. 7. Experimental configuration for pulse measurements.

of the facet-PhC cavity [7]. In our experiment, this condition is avoided by using 1-mm-long samples and 500 fs pulses. A bandgap does not exist for TM polarization ($\mathbf{E} \parallel$ etched holes) with this dielectric configuration, and as such there is no lateral confinement within the CCW, TM polarized light diffracts through the device resulting in very low transmission.

IV. EXPERIMENT

Previous measurements of pulses propagating through PhC waveguides have been restricted to spectral or time of flight methods [8]–[12]. Nonlinear analysis of the pulse duration has not been used as a direct measurement of the PhC dispersion. The main difficulties associated with this type of measurement pertain to the obtainable signal level. The dominant loss mechanism is simply the insertion loss into the ridge waveguide. A reflection loss also exists at the ridge/PhC interface due to the impedance mismatch. Propagation loss in these CCWs is not yet fully understood and requires a full 3-D analysis that is currently being conducted. An initial 3-D FDTD estimation points to a loss of the order of 10 dB for this PhC device. The transmission spectra shown in Fig. 6 displays the CW data normalized to the lensed fiber-to-fiber transmission, and indicates a total loss of >20 dB. From comparison with blank ridge waveguides, the PhC is measured to contribute approximately 10 dB of this loss (PhC insertion and propagation loss) the remainder accounted for by the ridge waveguide insertion loss. By operating at the correct wavelength, the availability of two optical amplifiers (EDFAs) allows both the pulsed laser source and the transmitted signal to be amplified, giving a large enough signal for the nonlinear characterization (autocorrelation) of the pulses. The balance of preamplification to postamplification is important in ensuring sufficient gain to overcome losses, while minimizing power within the PhC device to avoid optical nonlinearities. This is further assisted by careful choice of material and laser source to evade these nonlinear processes in the device, which constitute a further possible source of loss [7].

The experimental configuration is shown in Fig. 7. The pulse source comprises a gain switched DFB laser operating at 1536.1 nm with a repetition rate of 1 GHz. The pulses are passed, in turn, through a length of dispersion compensated fiber (DCF) to provide linear pulse compression of the chirped pulse, a length of dispersion shifted fiber (DSF) followed by standard single mode fiber (SMF) to provide nonlinear compression and finally a dispersion-imbalanced loop mirror (DILM) which acts to suppress the pulse pedestal and broaden the pulse spectrum [13]. After compression the pulse is transform limited to a minimum width of 500 fs, as shown in Fig. 8(a), and has a spectral width

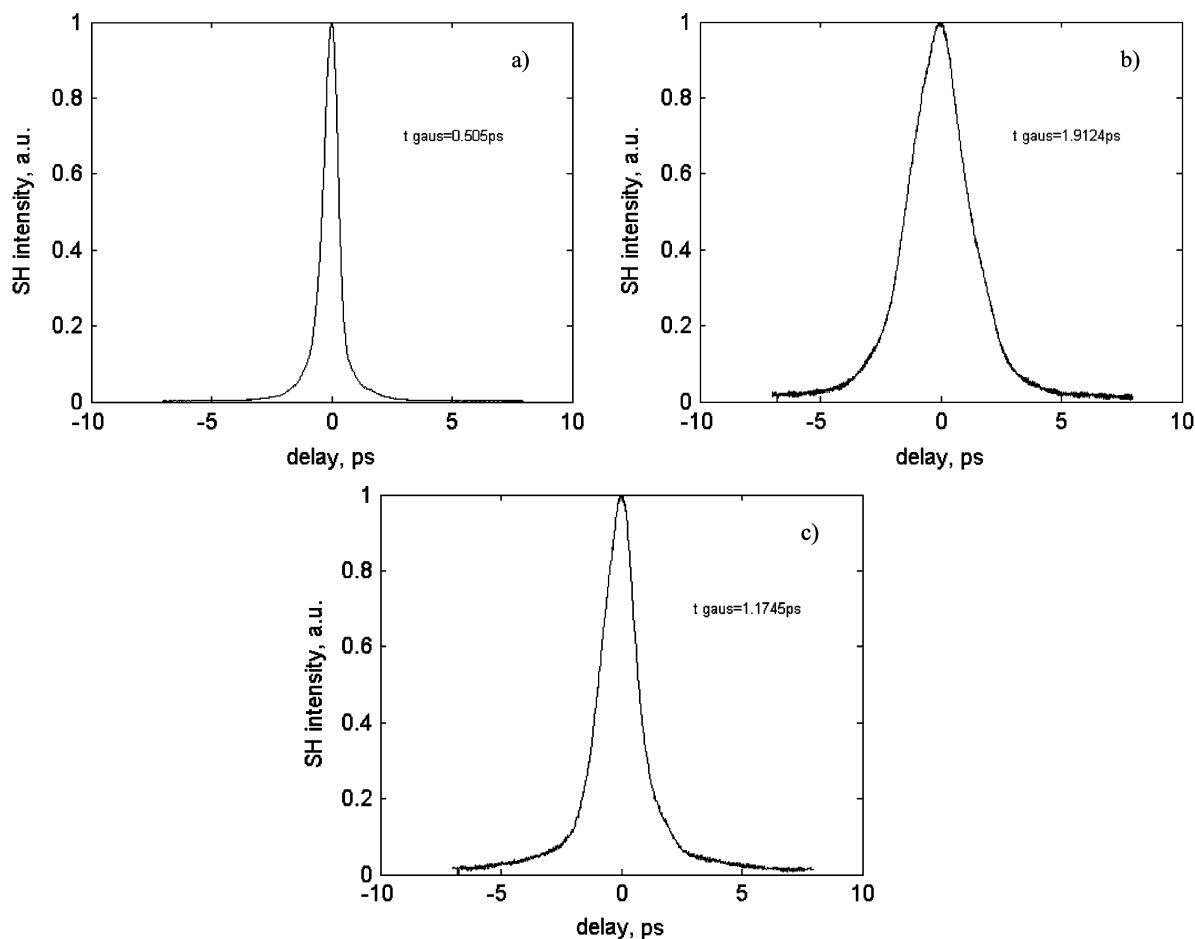


Fig. 8. (a) Autocorrelation of input transform limited pulse observed autocorrelation traces of pulse for same fiber length after transmission; (b) through blank waveguide; (c) through waveguide with L2in1 PhC.

of 7 nm. Due to this short minimum duration, increasing or decreasing the overall length of SMF in the system downstream from the DILM can reliably broaden the pulse. This technique is used to allow pulse compression measurements to be carried out at a range of different input pulsewidths. In order to assess the absolute pulse compression performance of the dispersive PhC, a comparative measurement is made of the pulse transmission through both the PhC and an identical waveguide without a PhC. With the presence of short pulses in such highly confined cavities, one must be wary of nonlinear behavior, and its effect on pulse propagation. An entirely linear behavior was observed at the available power levels [7].

Comparison of autocorrelation measurements of the transmitted pulses is used to determine the dispersion of the PhC waveguide. By adding extra fiber to the system, we can controllably increase the pulsewidth from the initial 500 fs. Examples of the pulses transmitted through a control waveguide [Fig. 8(b)] and the PhC waveguide [Fig. 8(c)] demonstrate the compression effect. We clearly observe that the pulse that passes through the PhC has a significantly shorter duration (1.17 ps) than that passing through the control waveguide (1.91 ps). The PhC CCW, which is only 8 μm long, is therefore responsible for a pulse compression of 40%.

A series of measurements have been carried out to investigate the compression effect of the PhC as the length of SMF

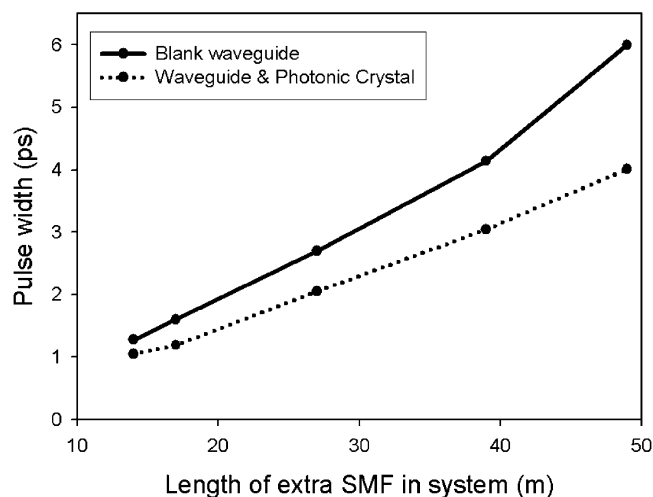


Fig. 9. Variation of pulsewidth with an increase in length of SMF in system.

within the system is greatly increased. Fig. 9 shows the measured pulsewidths for both the control waveguide and the PhC waveguide, indicating pulse duration reductions of up to 2 ps across the range of SMF lengths measured.

Comparisons of the length of fiber in the system required to produce a given pulse duration through the blank waveguide with the pulse durations observed for the PhC waveguide were

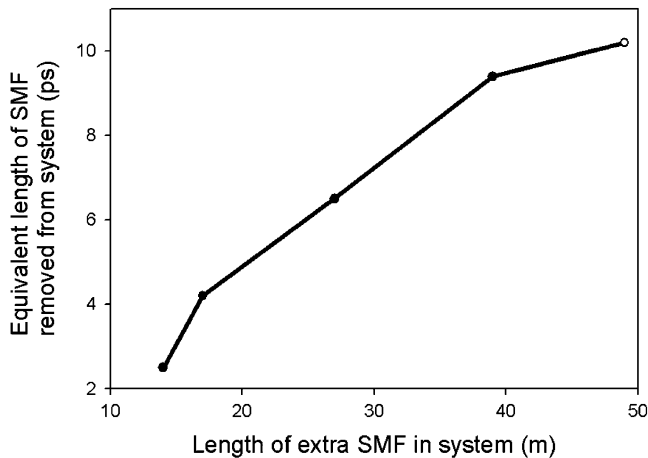


Fig. 10. Equivalent length of SMF required to produce compression observed due to PhC.

then made. These values demonstrate the length of fiber that needs to be removed to produce pulse compression equivalent to that achieved by the PhC. Fig. 10 illustrates these values, showing that the 8- μm -long PhC waveguide can achieve compressions equivalent to SMF lengths of up to 10 m. Thus the dispersion induced by the PhC is $>10^6$ larger than that of standard single mode fiber at these wavelengths.

V. CONCLUSION

We report the first direct measurement of pulse compression using the large group velocity dispersion available from planar PhC CCWs. Finite length devices have been successfully fabricated in a GaAs/AlGaAs heterostructure and modeled using both 2-D FDTD and 2-D EME. The equivalent dispersion value is $>10^6$ times larger than that available from standard single-mode fiber, in the key telecommunications 1550 nm EDFA window.

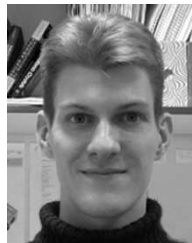
ACKNOWLEDGMENT

The calculation of the photonic bandstructure was performed by S. Boscolo and M. Midrio at the University of Udine, Italy. The help of T. Davies at Photon Design is greatly appreciated.

REFERENCES

- [1] M. Notomi, K. Yamada, A. Shinya, J. Takahashi, C. Takahashi, and I. Yokohama, "Extremely large group-velocity dispersion of line-defect waveguides in photonic crystal slabs," *Phys. Rev. Lett.*, vol. 87, p. 253 902, 2001.
- [2] E. Ozbay, M. Bayindir, I. Bulu, and E. Cubukcu, "Investigation of localized coupled-cavity modes in two-dimensional photonic bandgap structures," *IEEE J. Quantum Electron.*, vol. 38, p. 837, 2002.
- [3] T. J. Karle, D. H. Brown, R. Wilson, M. Steer, and T. F. Krauss, "Planar photonic crystal coupled cavity waveguides," *IEEE J. Select. Topics Quantum Electron.*, vol. 8, p. 909, 2002.
- [4] S. G. Johnson and J. D. Joannopoulos, "Block-iterative frequency-domain methods for Maxwell's equations in a planewave basis," *Opt. Express*, vol. 8, p. 173, 2001.
- [5] H. Benisty, D. Labilloy, C. Weisbuch, C. J. M. Smith, T. F. Krauss, D. Cassagne, A. Béraud, and C. Jouanin, "Radiation losses of waveguide-based two-dimensional photonic crystals: Positive role of the substrate," *Appl. Phys. Lett.*, vol. 76, p. 532, 2000.
- [6] M. Qiu, "Effective index method for heterostructure-slab-waveguide-based two-dimensional photonic crystals," *Appl. Phys. Lett.*, vol. 81, p. 1163, 2002.

- [7] Y. J. Chai, C. N. Morgan, T. J. Karle, R. V. Penty, T. F. Krauss, and I. H. White, "Propagation of picosecond pulses through photonic crystal waveguides at C-band region," in *Proc. LEOS*, vol. 2002, 2002, p. 881.
- [8] M. D. Rahn, A. M. Fox, M. S. Skolnick, and T. F. Krauss, "Propagation of ultrashort nonlinear pulses through two-dimensional AlGaAs high-contrast photonic crystal waveguides," *J. Opt. Soc. Amer. B*, vol. 19, p. 716, 2002.
- [9] N. Kawai, K. Inoue, N. Ikeda, N. Carlsson, Y. Sugimoto, K. Asakawa, S. Yamada, and Y. Katayama, "Transmittance and time-of-flight study of AlxGal-xAs-based photonic crystal waveguides," *Phys. Rev. B*, vol. 63, p. 153 313, 2001.
- [10] K. Inoue, N. Kawai, Y. Sugimoto, N. Carlsson, N. Ikeda, and K. Asakawa, "Observation of small group velocity in two-dimensional AlGaAs-based photonic crystal slabs," *Phys. Rev. B*, vol. 65, p. 121 308, 2002.
- [11] M. C. Netti, C. E. Finlayson, J. J. Baumberg, M. D. B. Charlton, M. E. Zoorob, J. S. Wilkinson, and G. J. Parker, "Separation of photonic crystal waveguides modes using femtosecond time-of-flight," *Appl. Phys. Lett.*, vol. 81, p. 3927, 2002.
- [12] Y. Sugimoto, S. Lan, S. Nishikawa, N. Ikeda, H. Ishikawa, and K. Asakawa, "Design and fabrication of impurity band-based photonic crystal waveguides for optical delay lines," *App. Phys. Lett.*, vol. 81, p. 1946, 2002.
- [13] I. Y. Khrushchev, I. H. White, and R. V. Penty, "High-quality laser diode pulse compression in dispersion-imbalanced loop mirror," *Electron. Lett.*, vol. 34, p. 1009, 1998.



T. J. Karle (S'03) received the M.Phys. (Hons.) degree in physics (with study in Europe) from the University of Manchester, U.K., in 1999 with the degree of with Study in Europe. In 2000 he received the M.Sc. degree in optoelectronic and laser devices with distinction, jointly from Heriot Watt and St. Andrews Universities.

He then worked as a design engineer with Renishaw Plc, conditioning diode laser light for Raman spectroscopy. He joined the Photonic Crystal Research Group at St. Andrews University in 2001 and is currently pursuing the Ph.D. degree while researching the dispersive properties of 2-D photonic bandgap structures for integrated optics.

Mr. Karle was the recipient of the Neil Forbes/Scottish Enterprise Prize for Excellence in Optoelectronics.



Y. J. Chai was born in Malaysia in 1978. He received the B.Eng. degree in electrical and electronics engineering from the University of Bristol in 1999.

He is currently a Ph.D. degree student with the Photonic System Group, University of Cambridge, U.K., where his research interests include optical short pulse generation and compression, nonlinear optics, and WDM transmission systems.

C. N. Morgan (M'02) received the B.A. and M.Eng. degrees in electrical and information sciences from the University of Cambridge, U.K., in 1998, and the Ph.D. degree from the University of Bristol in 2003. His Ph.D. work concentrated on the design, fabrication, and manufacture of novel planar demultiplexer components.

He is currently a Member of the Photonic Systems Group, University of Cambridge, where his research interests include passive components, photonic crystals, and active polymers.

I. H. White (S'82-M'83-SM'00), photograph and biography not available at the time of publication.



T. F. Krauss received the Dipl.-Ing. degree in photographic engineering in 1989 from the FH Koeln, Germany, where he was involved in integrated optics research, and the Ph.D. degree from the University of Glasgow, U.K., in 1992 for his work on semiconductor laser rings, where he demonstrated low threshold current levels and greatly improved external device efficiency.

In 1993, he started work on photonic crystals when he won an EPSRC Research Fellowship in the area of photonic bandgaps, thereby initiating a new field at the University of Glasgow, followed by a Royal Society Research Fellowship in 1995. He is one of the pioneers of semiconductor-based photonic crystals and made the first demonstration of 2-D photonic band-gap effects at optical wavelengths in 1996. In 1997, he spent a year at the California Institute of Technology, Pasadena, working on efficient photonic crystal based light emitters. In March 2000, he joined St. Andrews University, U.K., where he is currently setting up a semiconductor microfabrication laboratory. He became a Personal Chair in Optoelectronics with the School of Physics and Astronomy, University of St. Andrews, in 2000, where he set up a Photonic Crystal Research Group and a Semiconductor Microfabrication Facility. He is grant holder of several U.K. research projects.

Dr. Krauss is Coordinator of the European Research Project "PICCO." He was Organizer and Chairman of the trend-setting Workshop "PECS3" in St. Andrews in June 2001 and is on the committee of several other workshops and summer schools, including MRS and PECS. In 2002, he was elected a Fellow of the Royal Society of Edinburgh.